

High-Speed USB 2.0 (480-Mbps) 1:2 Multiplexer/Demultiplexer Switch

FEATURES

- -3dB Bandwidth: 550MHz
- Supply Range: +1.8V to +5.5V
- R_{ON} is Typically 6Ω
- Fast Switching Times: t_{ON} 20ns
 - toff 15ns
- Break-Before-Make Switching
- Low Power Consumption (1µA Maximum)
- Rail-to-Rail Input and Output Operation
- Extended Industrial Temperature Range: -40°C to +85°C
- MicroSIZE PACKAGES: MSOP-10

APPLICATIONS

- Routes Signals for USB 1.0, 1.1, and 2.0
- MP3 and Other Personal Media Players
- Portable Instrumentation
- USB Switching
- Digital Cameras
- Set-Top Box
- Cell Phones
- PDAs

DESCRIPTION

The RS2227 is a high-speed, low-power double-pole/double-throw (DPDT) analog switch with single Enable. It is designed to operate from 1.8 V to 5.5 V.

The RS2227 has a bus-switch enable pin, \overline{OE} , that can place the signal paths in high impedance. This allows the user to isolate the bus when it is not in use and consume less current.

The RS2227 is a high-bandwidth switch specially designed for the switching of high-speed USB2.0 signals in handset and consumer applications, such as cell phones, digital cameras, and notebooks with hubs or controllers with limited USB I/Os.

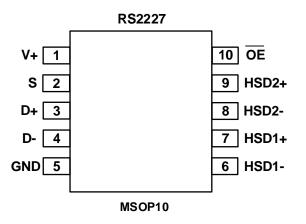
The RS2227 is available MSOP-10 package. It operates over an ambient temperature range of -40°C to +85°C.

HSD1+ HSD2+ HSD1-HSD2-D-HSD2-D-HSD2-Control

Functional Block Diagram



PIN CONFIGURATIONS



PIN DESCRIPTION

NAME	PIN	FUNCTION
V+	1	Power Supply
GND	5	Ground
S	2	Select Input
OE	10	Output Enable
HSD1+, HSD2+	7,9	
HSD1-, HSD2-	6,8	Data Port
D+, D-	3,4	

FUNCTION TABLE

ŌĒ	S	HSD1+, HSD1-	HSD2+, HSD2-
0	0	ON	OFF
0	1	OFF	ON
1	Х	OFF	OFF

X =Don't care



ABSOLUTE MAXIMUM RATINGS⁽¹⁾

V+ to GNDOV to 6V Analog, Digital Voltage Range $^{(2)}$ 0.3 to (V+) + 0.3V Continuous Current HSDn or Dn±100mA Peak Current HSDn or Dn±150mA Storage Temperature65°C to +150°C Operating Temperature65°C to +85°C Junction Temperature		
Continuous Current HSDn or Dn±100mA Peak Current HSDn or Dn±150mA Storage Temperature65°C to +150°C Operating Temperature40°C to +85°C Junction Temperature	V+ to GND	0V to 6V
Peak Current HSDn or Dn	Analog, Digital Voltage Range ⁽²⁾	.– 0.3 to (V+) + 0.3V
Storage Temperature	Continuous Current HSDn or Dn	±100mA
Operating Temperature	Peak Current HSDn or Dn	±150mA
Junction Temperature	Storage Temperature	−65°C to +150°C
Lead Temperature (Soldering, 10s)260°C ESD Susceptibility HBM	Operating Temperature	−40°C to +85°C
ESD Susceptibility HBM	Junction Temperature	150°C
HBM	Lead Temperature (Soldering, 10s)	260°C
	ESD Susceptibility	
MM200V	НВМ	3000V
	MM	200V

(1) Stresses above these ratings may cause permanent damage. Exposure to absolute maximum conditions for extended periods may degrade device reliability. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those specified is not implied.



ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

PACKAGE/ORDERING INFORMATION

PRODUCT	ORDERING NUMBER	TEMPERATURE RANGE	PACKAGE LEAD	PACKAGE MARKING	PACKAGE OPTION
RS2227	RS2227XN	-40°C ~+85°C	MSOP-10	RS2227	Tape and Reel,3000

⁽²⁾ Input terminals are diode-clamped to the power-supply rails. Input signals that can swing more than 0.3V beyond the supply rails should be current-limited to 10mA or less.



ELECTRICAL CHARACTERISTICS

 $(V + = +1.8V \text{ to } +5.5V, \text{GND} = 0V, V_{IH} = +1.5V, V_{IL} = +0.5V, T_A = -40^{\circ}\text{C} \text{ to } +85^{\circ}\text{C}$. Typical values are at V+ = +3.3V, T_A = +25^{\circ}\text{C}, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	TA	MIN	TYP	MAX	UNITS
ANALOG SWITCH							
Analog I/O Voltage (HSD1+, HSD1-, HSD2+, HSD2-)	VIS		-40°C to +85°C	0		V+	V
On-Resistance	Ron	V+ = 3.0V, V _{IS} = 0V to 0.4V,	+25°C		6	10	Ω
	IXON	I _D = 8mA, Test Circuit 1	-40°C to +85°C			10.5	
On-Resistance Match		V + = 3.0V, V_{IS} = 0V to 0.4V,	+25°C		0.15	0.6	Ω
Between Channels	Δηση	I _D = 8mA, Test Circuit 1	-40°C to +85°C			1.6	Ω
	Rflat(on)	V+ = 3.0V, V_{IS} = 0V to 1.0V, I _D = 8mA, Test Circuit 1	+25°C		5	7	Ω
On-Resistance Flatness			-40°C to +85°C			8	
Power Off Leakage Current (D+, D-)	Ioff	V+ = 0V, V _D = 0V to 3.6 V, V _S , V _{OE} = 0V or 3.6 V	-40°C to +85°C			1	μA
Increase in I₊ per Control Voltage	Ісст	V+ = 4.3V, V _S or $V_{\overline{OE}}$ = 2.6 V	-40°C to +85°C			40	μA
Source Off Leakage Current	HSD2(OFF)	V+ = 3.6V, V _{IS} = 3.3V/ 0.3V, V _D = 0.3V/ 3.3V	-40°C to +85°C			1	μA
Channel On Leakage Current	HSD2(ON) HSD1(ON)	V+ = 3.6V, V _{IS} = $3.3V/0.3V$, V _D = $0.3V/3.3V$ or floating	-40°C to +85°C			1	μA
DIGITAL CONTROL INPUTS ⁽¹⁾							
Input High Voltage	VIH		-40°C to +85°C	1.6			V
Input Low Voltage	VIL		-40°C to +85°C			0.5	V
Input Leakage Current	lin	V+ = 3.0V, V _S , $V_{\overline{OE}}$ = 0V or V+	-40°C to +85°C			1	μA

(1) All unused digital inputs of the device must be held at VIO or GND to ensure proper device operation.

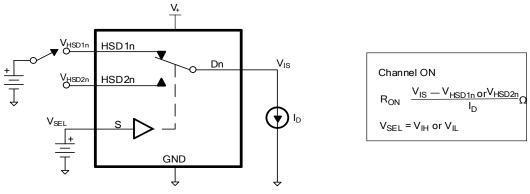


ELECTRICAL CHARACTERISTICS (continued) (V+ = +1.8V to +5.5V, GND = 0V, V_{IH} = +1.5V, V_{IL} = +0.5V, T_A = -40°C to + 85°C. Typical values are at V+ = +3.3V, T_A = +25°C, unless otherwise noted.)

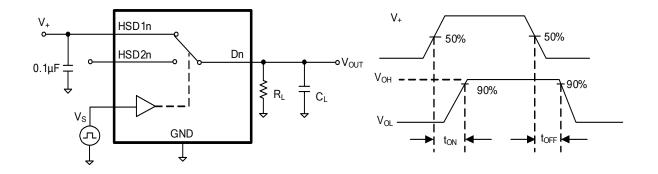
PARAMETER	SYMBOL	CONDITIONS	TEMP	MIN	ТҮР	MAX	UNITS
DYNAMIC CHARACTERISTI	cs						
Turn-On Time	tоn	V _{IS} = 0.8V, R _L = 50Ω,	+25°C		20		ns
Turn-Off Time	toff	$C_L = 10 pF$, Test Circuit 2	+25°C		15		ns
Break-Before-Make Time Delay	t _D	$V_{IS} = 0.8V, R_{L} = 50\Omega,$ $C_{L} = 10pF$, Test Circuit 3	+25°C		4		ns
Propagation Delay	t _{PD}	$R_L = 50\Omega$, $C_L = 10pF$	+25°C		0.35		ns
Off Isolation	Oiso	Signal = 0dBm, R∟ = 50Ω, f = 250MHz, Test Circuit 4	+25°C		-35		dB
Channel-to-Channel Crosstalk	Xtalk	Signal = 0dBm, R⊾ = 50Ω, f = 250MHz, Test Circuit 5	+25°C		-40		dB
-3dB Bandwidth	BW	Signal = 0dBm, R _L = 50Ω, C _L = 5pF, Test Circuit 6	+25°C		550		MHz
Channel-to-Channel Skew	tskew	R _L = 50Ω, C _L = 10pF	+25°C		0.05		ns
Charge Injection Select Input to Common I/O	Q	V_G = GND, C_L = 1.0nF, R_G = 0 Ω , Q = $C_L x V_{OUT}$, Test Circuit 7	+25°C		11		рС
HSD+, HSD-, D+, D- ON Capacitance	Сом		+25°C		7		pF
POWER REQUIREMENTS						_	
Power Supply Range	V+		-40°C to +85°C	1.8		5.5	V
Power Supply Current	I+	V+ = 3.0V, V _S , $V_{\overline{OE}}$ = 0V or V+	-40°C to +85°C			1	μA



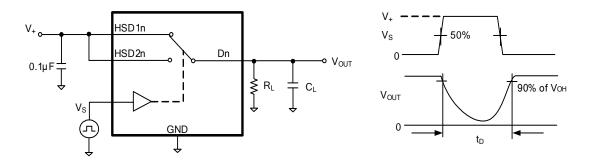
Parameter Measurement Information



Test Circuit 1. ON-State Resistance (RoN)

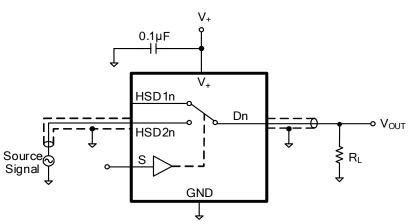


Test Circuit 2. Turn-On (ton) and Turn-Off Time (toff)

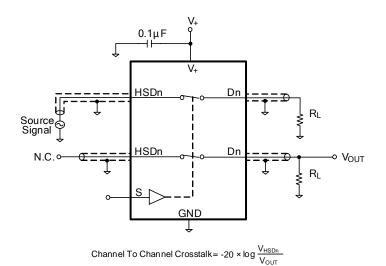


Test Circuit 3. Break-Before-Make Time (t_D)

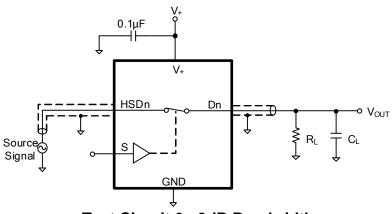




Test Circuit 4.0FF Isolation (OISO)



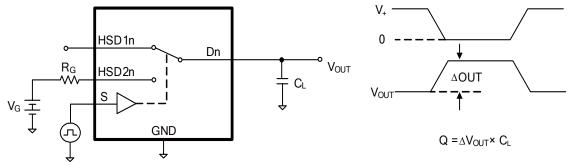
Test Circuit 5. Channel-to-Channel Crosstalk



Test Circuit 6. -3dB Bandwidth

7









APPLICATION NOTES

There are many USB applications in which the USB hubs or controllers have a limited number of USB I/Os. The RS2227 solution can effectively expand the limited USB I/Os by switching between multiple USB buses in order to interface them to a single USB hub or controller. RS2227 can also be used to connect a single controller to two USB connectors or controllers.

Design requirements of the USB 1.0, 1.1, and 2.0 standards should be followed. It is recommended that the digital control pins S and \overline{OE} be pulled up to V+ or down to GND to avoid undesired switch positions that could result from the floating pin.

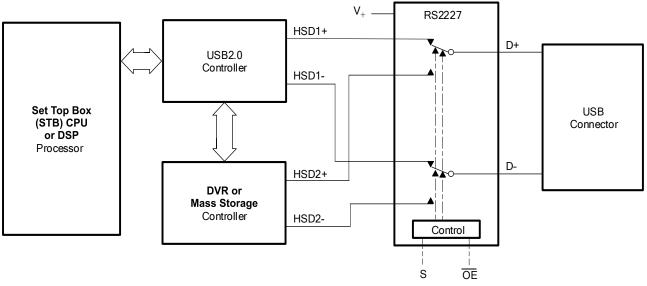
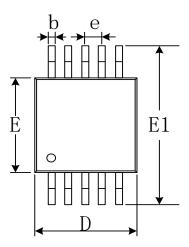
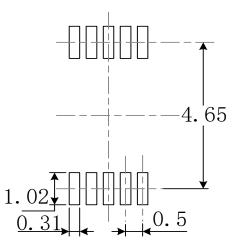


Figure 1. Application Diagram

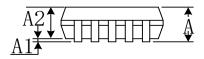


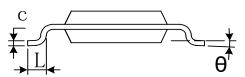
PACKAGE OUTLINE DIMENSIONS MSOP-10





RECOMMENDED LAND PATTERN (Unit: mm)





Symbol	Dimensions I	n Millimeters	Dimensions In Inches		
Symbol	Min	Мах	Min	Мах	
A	0.820	1.100	0.032	0.043	
A1	0.020	0.150	0.001	0.006	
A2	0.750	0.950	0.030	0.037	
b	0.180	0.280	0.007	0.011	
с	0.090	0.230	0.004	0.009	
D	2.900	3.100	0.114	0.122	
е	0.50(BSC)	0.020(BSC)		
E	2.900	3.100	0.114	0.122	
E1	4.750	5.050	0.187	0.199	
L	0.400	0.800	0.016	0.031	
θ	0°	6°	0°	6°	

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